

Specification for Approval

DEVICE NUMBER: BPD-BQBA31

• CUSTOMER:

SAMPLES ATTACHED AREA

PAGE DATE	1	2	3	4	5				CONTENTS
2017/3/9	1.0	1.0	1.0	1.0	1.0				Initial Released
2022/10/12	1.1	1.1	1.1	1.1	1.1				Modify Electrical Characteristics
								A	
							A STATE OF THE PARTY OF THE PAR	h	
						1	A SPA		
					2	Sept.			•
_				1		September 1	No.	4	

FOR CUSTOMER'S APPROVAL STAMP OR SIGNATURE

APPROVED	PURCHASE	MANUFACTURE	QUALITY	ENGINEERING
A				
	A CONTRACTOR OF THE PARTY OF TH			
	7			
11/1	Service.			

佰鴻工業股份有限公司 BRIGHT LED ELECTRONICS CORP. 新北市板橋區和平路 19 號 3 樓 3F., No.19, He Ping Road, Ban Qiao Dist., New Taipei City, Taiwan

Tel: +886-2-29591090

Fax: +886-2-29547006/29558809

www.brtled.com

Approved By	Confirmed By	Prepared By
曾	郭	劉
2022.10.12	2022.10.12	2022.10.12
慶 霖	初 榮	丹 丹



BPD-BQBA31

END- LOOK PACKAGE PIN PHOTO DIODE

I Features

- 1. Linear response vs. irradiance
- 2. Fast switching time
- End-looking Package ideal for space limited applications
- 4. Lens Appearance: Black
- This product doesn't contain restriction Substance, comply RoHS standard.

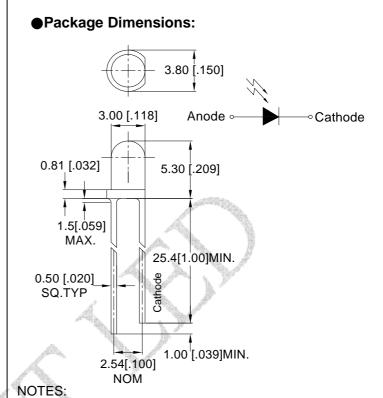
I Description

The BPD-BQBA31device consists of a PIN silicon photodiode molded in a black epoxy package which allows spectral response infrared light wavelengths.

The receiving angleprovides relatively even reception over a large area.

The end-looking package is designed for easy PC board mounting.

This photodiode is mechanically and spectrally matched to BRIGHT's GaAs and GaAlAs series of infrared emitting diodes.



- 1. All dimensions are in millimeters (inches).
- 2. Tolerance is ±0.25mm (0.01') unless otherwise specified.
- 3. Lead spacing is measured where the leads emerge from the package
- 4. Specifications are subject to change without notice

I Absolute Maximum Ratings(Ta=25°C)

Parameter	Maximum Rating	Unit		
Power Dissipation	100	mW		
Reverse Breakdown Voltage	60V			
Operating Temperature	-40°℃~+85°℃			
Storage Temperature Range	-45°℃~+	85 ℃		



BPD-BQBA31

I Electrical Characteristics (Ta=25°C unless otherwise noted)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Reverse Light Current	IL	-	28	-	μA	V _R =5V, Ee=1mW/cm ²
Reverse Dark Current	I _D	-	-	30	nA	V _R =10V, Ee=0 mW/cm ²
Reverse Break down Voltage	$V_{(BR)}$	35	-	-	V	I _R =100μA
Forward Voltage	V _F	-	-	1.3	V	I _F =10mA
Spectral range of sensitivity	λ10%	820	940	1100	nm	
Wavelength of max sensitivity	λр		940		nm	
Total Capacitance	Ст	-	5	-	PF	V _R =5V, Ee=0, f=1.0MHZ
Rise Time/ Fall Time	tr/tf	-	10	- 4	ns	V_R =20V, λ =940nm, RL=50 Ω
Angle of sensitivity	2θ _{1/2}	-	45	. -	deg	

I Typical Optical-Electrical Characteristic Curves

Fig1.Relative Responsivity vs.Wavelength

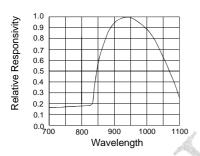


Fig3.Normalized Light Current vs
Reverse Voltage

1.20

1.10

1.10

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

1.00

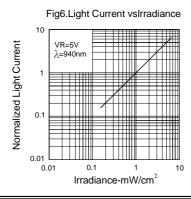
1.00

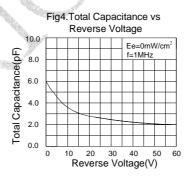
1.00

1.00

1.00

1.00





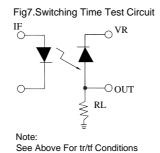
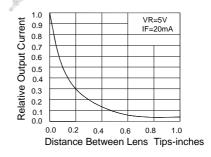
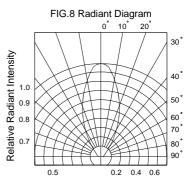


Fig2.Coupling Characteristics

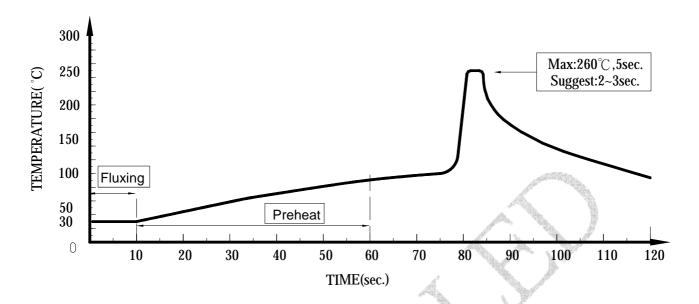






BPD-BQBA31

Dip Soldering



- Please avoid any external stress applied to the lead-frames and epoxy while the LEDs are at high temperature, especially during soldering
- 2. DIP soldering and hand soldering should not be done more than one time.
- 3. After soldering, avoid the epoxy lens from mechanical shock or vibration until the LEDs are back to room temperature.
- 4. Avoid rapid cooling during temperature ramp-down process
- Although the soldering condition is recommended above,soldering at the lowest possible temperature is feasible for the LEDs

IRON Soldering

A: Max: 350°C Within 3 sec. One time only.

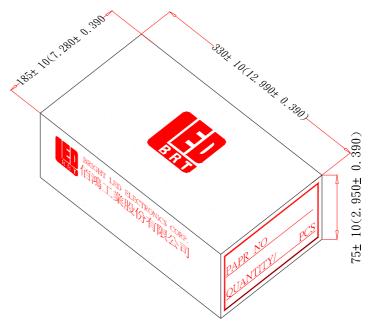
B: The products of 3mm without flange, welding condition of flat plate PCB Max:

350 $^{\circ}$ Within 2 sec. One time only

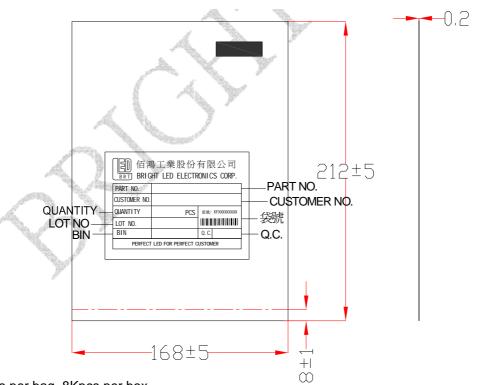


BPD-BQBA31

Tapping and packaging specifications(Units: mm)



I Packaging Bag Dimensions



- Notes:
 - 1 . 1000pcs per bag, 8Kpcs per box.
 - 2 · All dimensions are in millimeters(inches).
 - 3 · Specifications are subject to change without notice.



BPD-BQBA31

Phototransistor Specification

2 Commodity: Phototransistor

2 Collector Current Bin Limits (V_R=5V, Ee=1mW/cm²)

BIN CODE	Min.(uA)	Max.(uA)
W	17.8	21.3
X	21.3	25.6
Y	25.6	30.8
Z	30.8	36.9
1	36.9	44.3
2	44.3	53.2

NOTES: Tolerance of measurement of Radiant Intensity :±15%

单击下面可查看定价,库存,交付和生命周期等信息

>>BRT(佰鸿工业)